

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application No.	:	10/567,729	Confirmation No. 7682
Applicant	:	Kazutoshi Kojima et al.	
371(c) Filed	:	February 1, 2006	
Art Unit	:	2814	
Examiner	:	Wael M. Fahmy	
Customer No.	:	00270	
Title	:	SILICON CARBIDE EPITAXIAL WAFER, METHOD FOR PRODUCING SUCH WAFER, AND SEMICONDUCTOR DEVICE FORMED ON SUCH WAFER	

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**RESPONSE TO NOTICE OF NON-COMPLIANT AMENDMENT**

Sir:

Please amend the above-identified patent application as follows.

**Amendments to the Specification** begin on page 2 of this paper.

**Remarks** begin on page 3 of this paper.